

500mW, High Speed Switching Diode

FEATURES

- Low power loss, high efficiency
- Ideal for automated placement
- High surge current capability
- Compliant to RoHS directive 2011/65/EU and in accordance to WEEE 2002/96/EC
- Halogen-free according to IEC 61249-2-21

APPLICATIONS

• Switching mode power supply (SMPS)

		•	
I _F	150	mA	
V_{RRM}	100	V	
I _{FSM}	2	Α	
V _F at I _F =100mA	1	V	
T _{J MAX}	150	°C	
Package	DO-35		
Configuration	Singal die		

KEY PARAMETERS
PARAMETER VALUE UNIT

Pb ROHS

MECHANICAL DATA

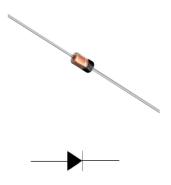
• Case: DO-35

 Packing code with suffix "G" means green compound (halogen-free)

• Terminal: Matte tin plated leads, solderable per J-STD-002

Polarity: Indicated by cathode band

• Weight: 125 ± 4 mg



ABSOLUTE MAXIMUM RATINGS (T _A = 25°C unless otherwise noted)					
PARAMETER	SYMBOL	1N4148	1N4448	1N914B	UNIT
Power dissipation	P_D		500		mW
Repetitive peak reverse voltage	V_{RRM}		100		V
Non-Repetitive peak forward surge current Pluse width = 1µs, Square wave	I _{FSM}	2		Α	
Non-Repetitive peak forward current	I _{FM}	450		mA	
Forward current	I _F	150		mA	
Junction temperature range	TJ	-65 to +150		°C	
Storage temperature range	T _{STG}	-65 to +150		°C	

THERMAL PERFORMANCE				
PARAMETER	SYMBOL	TYP	UNIT	
Junction-to-ambient thermal resistance	$R_{\Theta JA}$	240	°C/W	

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ELECTRICAL SPECIFICATIONS (T _A = 25°C unless otherwise noted)						
PARAMETER	CONDITIONS		SYMBOL	MIN	MAX	UNIT
Forward voltage per diode ⁽¹⁾	1N4448,1N914B	$I_F = 5 \text{ mA},$ $T_J = 25^{\circ}\text{C}$		0.62	0.72	V
	1N4148	$I_F = 10 \text{ mA},$ $T_J = 25^{\circ}\text{C}$	V _F	-	1.00	
	1N4448,1N914B	I _F = 100 mA, T _J = 25°C		-	1.00	
Reverse voltage	I _R = 100 μA, T _J = 25°C		.,	100	-	V
	I _R = 5 μA, T _J = 25°C		V_R	75	-	
Reverse current	V _R = 20 V, T _J = 25°C			-	25	nA
(2)	V _R = 75 V, T _J = 25°C		l _R	-	5	μA
Junction capacitance	1 MHz, V _R =0V		CJ	-	4	pF
Reverse recovery time	I_F = 10mA , V_R =6V, R_L = 100 Ω , I_{RR} = 1mA		t _{rr}	-	4	ns

Notes:

- 1. Pulse test with PW=0.3 ms
- 2. Pulse test with PW=30 ms

RDERING INFORMATION				
PART NO.	PACKAGE	PACKING		
1N4148 R0G	DO-35	10K / 14" Reel		
1N4148 R0	DO-35	10K / 14" Reel		
1N4148 A0G	DO-35	5K / Box(Ammo)		
1N4148 A0	DO-35	5K / Box(Ammo)		
1N4448 R0G	DO-35	10K / 14" Reel		
1N4448 R0	DO-35	10K / 14" Reel		
1N4448 A0G	DO-35	5K / Box(Ammo)		
1N4448 A0	DO-35	5K / Box(Ammo)		
1N914B R0G	DO-35	10K / 14" Reel		
1N914B R0	DO-35	10K / 14" Reel		
1N914B A0G	DO-35	5K / Box(Ammo)		
1N914B A0	DO-35	5K / Box(Ammo)		



CHARACTERISTICS CURVES

(T_A = 25°C unless otherwise noted)

Fig.1 Typical Forward Characteristics

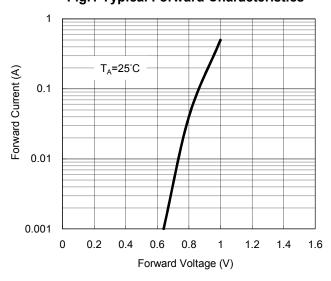


Fig. 2 Reverse Current VS. Reverse Voltage

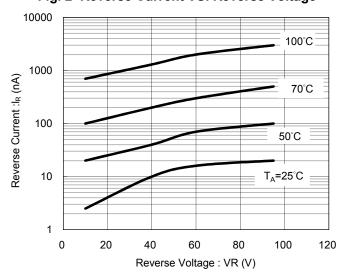


Fig.3 Admissible Power Dissipation Curve

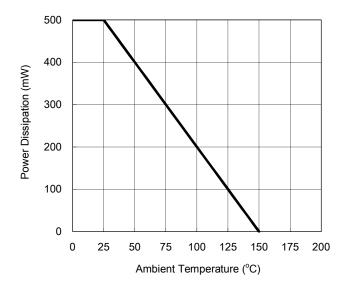
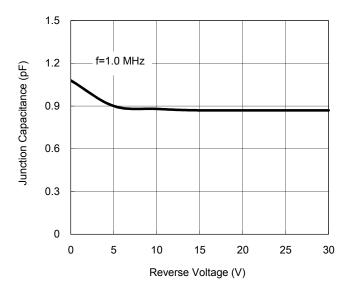


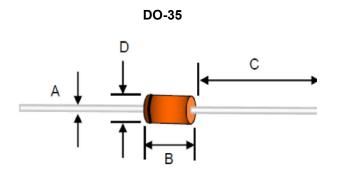
Fig.4 Typical Junction Capacitance





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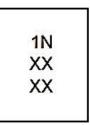
PACKAGE OUTLINE DIMENSION



DIM.	Unit (mm)		Unit (inch)		
DIW.	Min	Мах	Min	Max	
Α	0.34	0.60	0.013	0.024	
В	2.90	5.08	0.114	0.200	
С	25.40	38.10	1.000	1.500	
D	1.30	2.28	0.051	0.090	

MARKING DIAGRAM







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